OP505, OP505W, OP506, OP506W OP535

Obsolete (OP505D, OP506C, OP705A)

Features:

- T-1 package style
- Variety of sensitivity ranges
- Choice of narrow or wide receiving angle
- Small package size ideal for space-limited applications
- 0.050" [1.27 mm] or 0.100" [2.54 mm] Lead spacing





Description:

Each OP505 and OP506 devices consist of an NPN silicon phototransistor, the OP535 device consist of an NPN silicon photodarlington transistor. All of the devices are molded in a blue-tinted T-1 (3 mm) epoxy package.

The OP505 and OP535 devices have a narrow receiving angle that provides excellent on-axis coupling while the OP506 device has a wider receiving angle for those applications where a narrow receiving angle of the OP505 and OP535 is not required. The OP505W and OP506W device have the widest receiving angle and provides relatively even reception over a large area.

Devices are 100% production tested, using infrared light for close correlation with Optek's GaAs and GaAIAs emitters.

Please refer to Application Bulletins 208 and 210 for additional design information and reliability (degradation) data.

Please see your OPTEK representative for custom versions of these devices.

Applications:

- Space-limited applications
- Interruptive applications to detect media which is semitransparent to infrared light

Ordering Information						
Part Number	Sensor	Viewing Angle	Lead Spacing	Lead Length		
OP505A						
OP505B						
OP505C		20°	0.050"			
OP505D (Obsolete)			[1.27 mm]	0.50" [12.7 mm]		
OP505W	Transistor	90°				
OP506A						
OP506B		20°	0.100"			
OP506C (Obsolete)		20	[2.54 mm]			
OP506W		90°				
OP535A	Darlington					
OP535B	Danington	20°	0.050"			
OP705A (Obsolete)	R _{BE} Transistor	20	[1.27 mm]			

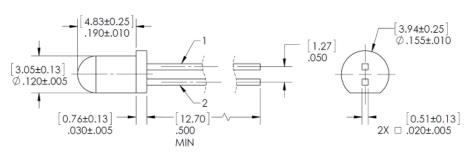


OP505, OP505W, OP506, OP506W OP535



Obsolete (OP505D, OP506C, OP705A)

OP505, OP535

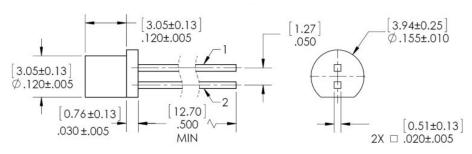


Pin #	Transistor			
1	Emitter			
2	Collector			

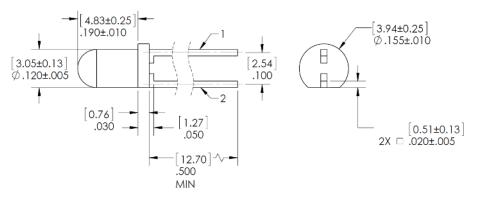
OP505, OP506 OP505W, OP506W



OP505W



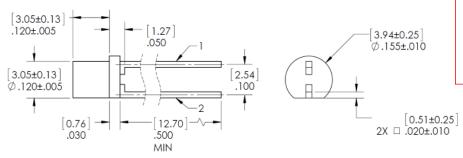
OP506







OP506W



TOLERANCES ARE ± .010" [.25] UNLESS OTHERWISE STATED DIMENSIONS ARE IN INCHES [MILLIMETERS]

CONTAINS POLYSULFONE

Methanol and isopropanol alcohols are recommended cleaning agents.
Housings are soluble in chlorinated hydrocarbons and keytones.
Highly activated or water soluble fluxes may damage body.
Testing reagents before use is recommended prior to use.

General Note

TT Electronics reserves the right to make changes in product specification without notice or liability. All information is subject to TT Electronics' own data and is considered accurate at time of going to print.

OP505, OP505W, OP506, OP506W OP535



Obsolete (OP505D, OP506C, OP705A)

Electrical Specifications

Absolute Maximum Ratings (T_A = 25° C unless otherwise noted)

Storage & Operating Temperature Range	-40° C to +100° C
Collector-Emitter Voltage (OP505, OP506, OP505W, OP506W)	30 V
Collector-Emitter Voltage (OP535)	15 V
Emitter-Collector Voltage (OP505 and OP506 series only)	5.0 V
Lead Soldering Temperature (1/16 inch (1.6 mm) from case for 5 seconds with soldering iron)	260° C
Power Dissipation	100 mW ⁽²⁾

Electrical Characteristics (T_A = 25° C unless otherwise noted) **OP505, OP506, OP505W, OP506W**

SYMBOL	PARAMETER	MIN	TYP	MAX	UNITS	TEST CONDITIONS
	On-State Collector Current OP505A, OP506A	4.30	-	-		N 5 N 5 0 50 N 1 2 N 1 2
I _{C(ON)}	OP505B, OP506B OP505C	2.15 1.10	- -	5.95 3.00	mA	$V_{CE} = 5 \text{ V}, E_E = 0.50 \text{ mW/cm}^2, \text{ Note 3}$
	OP505W, OP506W	0.10	-	-	mA	$V_{CE} = 5 \text{ V}, E_E = 0.75 \text{ mW/cm}^2, \text{ Note 3}$
V _{CE(SAT)}	Collector-Emitter Saturation Voltage OP505, OP506	-	-	0.40	V	$I_C = 250 \mu A$, $E_E = 0.5 \text{ mW/cm}^2$, Note 3
	OP505W, OP506W	-	-	0.40	V	$I_C = 50 \mu A$, $E_E = 0.75 \text{ mW/cm}^2$, Note 3
I _{CEO}	Collector-Dark Current	-	1	100	nA	$V_{CE} = 10 \text{ V}, E_E = 0$
$V_{(BR)CEO}$	Collector-Emitter Breakdown Voltage	30	-	-	V	$I_C = 100 \mu A, E_E = 0$
$V_{(BR)ECO}$	Emitter-Collector Breakdown Voltage OP505, OP506	5	- 1	-	V	I _E = 100 μA, E _E = 0
ΔΙ _C /ΔΤ	Relative I _C Changes with Temperature	-	1.00	-	%/°C	$V_{CE} = 5 \text{ V, } E_E = 1.0 \text{ mW/cm}^2$

Notes:

- (1) RMA flux is recommended. Duration can be extended to 10 seconds maximum when flow soldering. A maximum of 20 grams force may be applied to the leads when soldering.
- (2) Derate linearly 1.33 mW/° C above 25° C.
- (3) Light source is an unfiltered GaAs LED with a peak emission wavelength of 935 nm and a radiometric intensity level, which varies less than 10 % over the entire lens surface of the phototransistor being tested.
- (4) The knee point irradiance is defined as the irradiance required to increase $I_{C(ON)}$ to 50 μA .

OP505, OP505W, OP506, OP506W OP535



Obsolete (OP505D, OP506C, OP705A)

Electrical Specifications

Electrical Characteristics (T_A = 25° C unless otherwise noted) **OP535**

SYMBOL	PARAMETER	MIN	TYP	MAX	UNITS	TEST CONDITIONS
	On-State Collector Current					
I _{C(ON)}	OP535A	10.5	-	-	mA	$V_{CF} = 5 \text{ V}, E_F = 0.13 \text{ mW/cm}^2, \text{ Note 3}$
	OP535B	3.5	-	32.0	ША	$V_{CE} = 3$ $V_{CE} = 0.13$ HW/CHI, Note 3
V _{CE(SAT)}	Collector-Emitter Saturation Voltage	-	-	1.10	٧	$I_C = 400 \mu A$, $E_E = 0.13 \text{ mW/cm}^2$, Note 3
I _{CEO}	Collector-Dark Current		1	100	nA	V _{CE} = 10 V, E _E = 0
V _{(BR)CEO}	Collector-Emitter Breakdown Voltage	15.0	ı	-	V	I _C = 1.0 mA, E _E = 0
$V_{(BR)ECO}$	Emitter-Collector Breakdown Voltage	5.0	-	-	V	I _E = 100 μA, E _E = 0

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OP505, OP505W, OP506, OP506W OP535

600

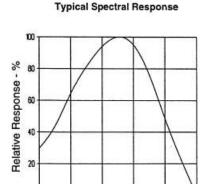
700

Obsolete (OP505D, OP506C, OP705A)



Performance

OP505A, OP505B, OP505C



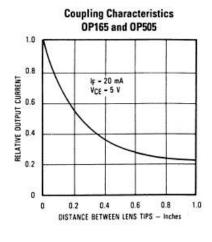
800

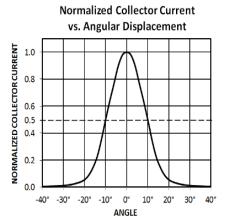
900

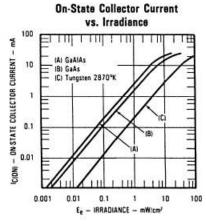
Wavelength - nm

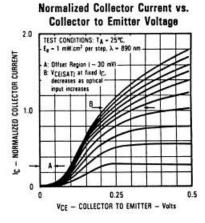
1000

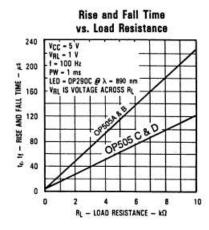
1100

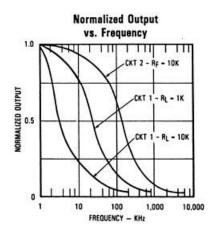


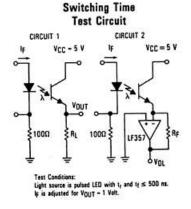












OP505, OP505W, OP506, OP506W **OP535**

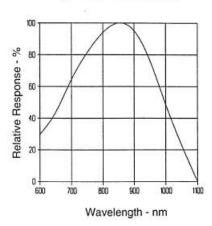




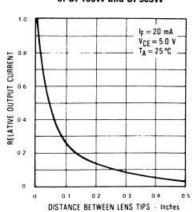
Performance

OP505W

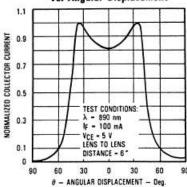
Typical Spectral Response



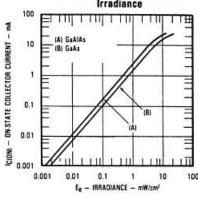
Coupling Characteristics of OP165W and OP505W



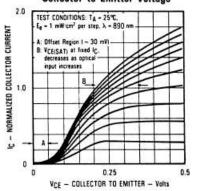
Normalized Collector Current vs. Angular Displacement



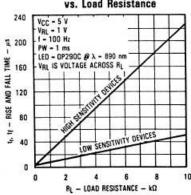
On-State Collector Current vs Irradiance



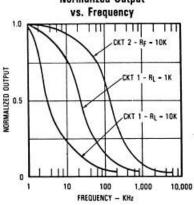
Normalized Collector Current vs. Collector to Emitter Voltage



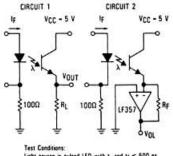
Rise and Fall Time vs. Load Resistance



Normalized Output



Switching Time Test Circuit



Light source is pulsed LED with t_f and $t_f \le 500$ ns. t_f is adjusted for $V_{OUT} = 1$ Volt.

OP505, OP505W, OP506, OP506W **OP535**

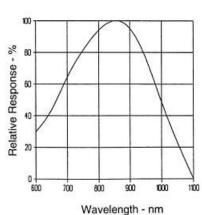


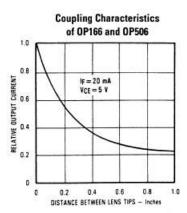


Performance

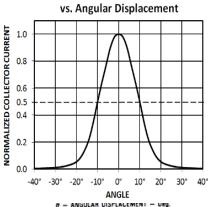
OP506A, OP506B



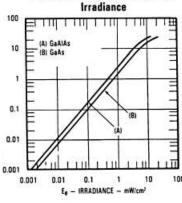




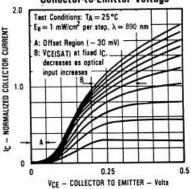
Normalized Collector Current



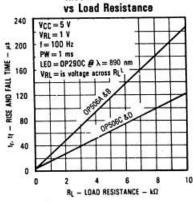
On-State Collector Current vs Irradiance



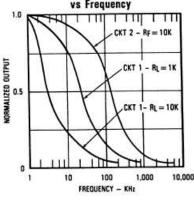
Normalized Collector Current vs Collector-to-Emitter Voltage



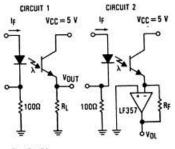
Rise and Fall Time



Normalized Output vs Frequency



Switching Time Test Circuit



Light source is pulsed LED with t_f and $t_f \le 500$ ns. IF is adjusted for $V_{OUT} = 1$ Volt.

OP505, OP505W, OP506, OP506W **OP535**

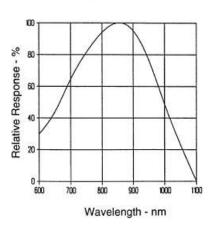




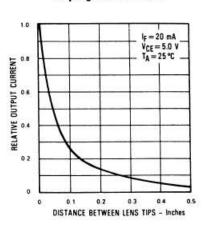
Performance

OP506W

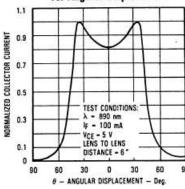




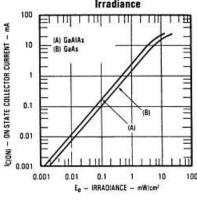
Coupling Characteristics



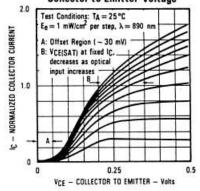
Normalized Collector Current vs. Angular Displacement



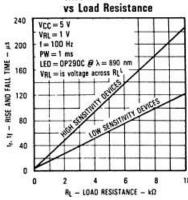
On-State Collector Current vs Irradiance



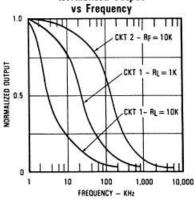
Normalized Collector Current vs Collector-to-Emitter Voltage



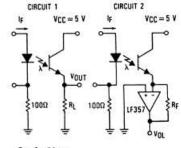
Rise and Fall Time



Normalized Output



Switching Time Test Circuit



Test Conditions: Light source is pulsed LED with t_f and $t_f \le 500$ ns. IF is adjusted for VOUT = 1 Volt.

OP505, OP505W, OP506, OP506W **OP535**

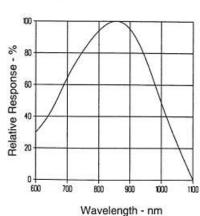
Obsolete (OP505D, OP506C, OP705A)



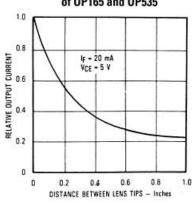
Performance

OP535A, OP535B, OP535D

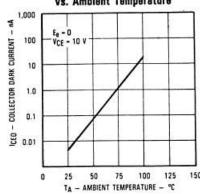




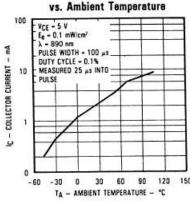
Coupling Characteristics of OP165 and OP535



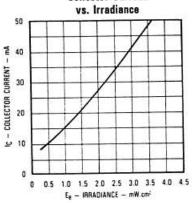
Collector Dark Current vs. Ambient Temperature



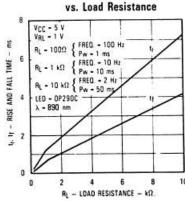
Collector Current vs. Ambient Temperature



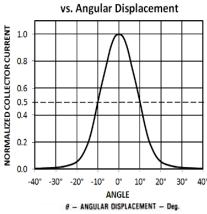
Collector Current



Rise and Fall Time



Normalized Collector Current



Switching Time Test Circuit

